

WS05MF

Order Code: WS05MF

Transient Voltage Suppressor

Features

- Solid-state silicon-avalanche technology
- 100 Watts Peak Pulse Power per Line (t_p=8/20μs)
- Low operating and clamping voltages
- Up to Four (4) Lines of Protection
- Working Voltages: 5 V
- Low Leakage Current

IEC COMPATIBILITY (EN61000-4)

- IEC 61000-4-2 (ESD) ±15kV (air), ±8kV (contact)
- IEC 61000-4-4 (EFT) 40A (5/50ns)
- IEC 61000-4-5 (Lightning) 5.5A (8/20µs)

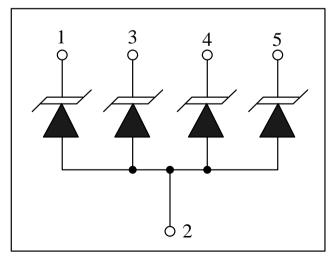
Mechanical Characteristics

- SOT-353 package
- Molding compound flammability rating: UL 94V-0
- Marking: Marking Code
- Packaging: Tape and Reel
- RoHS Compliant

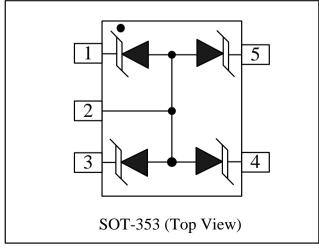
Applications

- Cellular Handsets & Accessories
- Personal Digital Assistants (PDAs)
- Notebooks & Handhelds
- Portable Instrumentation
- Digital Cameras
- MP3 Player

Circuit Diagram



Schematic & PIN Configuration

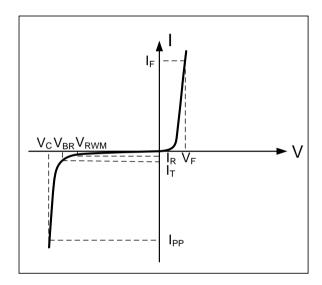




Absolute Maximum Rating			
Rating	Symbol	Value	Units
Peak Pulse Power (t _p =8/20μs)	Ррр	100	W
Peak Forward Voltage (I _F = 1A, t _p =8/20μs)	VFP	1.5	V
Operating Temperature	Tı	-55 to + 125	$^{\circ}$ C
Storage Temperature	Тѕтс	-55 to +150	°C

Electrical Parameters (T=25°C)

Symbol	Parameter
I PP	Maximum Reverse Peak Pulse Current
Vc	Clamping Voltage @ IPP
VRWM	Working Peak Reverse Voltage
IR	Maximum Reverse Leakage Current @ VRWM
V_{BR}	Breakdown Voltage @ I⊤
lτ	Test Current
lF	Forward Current
VF	Forward Voltage @ I _F



Electrical Characteristics

WS05MF						
Parameter	Symbol	Conditions	Minimum	Typical	Maximum	Units
Reverse Stand-Off Voltage	Vrwm				5.0	V
Reverse Breakdown Voltage	VBR	lτ=1mA	6.0			V
Reverse Leakage Current	l R	VRWM=5V,T=25°C			1	μΑ
Peak Pulse Current	I PP	t _p =8/20μs			5.5	Α
Clamping Voltage	Vc	IPP=1A, t _P =8/20μs			9.6	V
Clamping Voltage	Vc	IPP=5.5A, t _P =8/20µs		15	18	V
Junction Capacitance	Cj	Between I/O pins and Ground VR = 0V, f = 1MHz		22	25	pF

Typical Characteristics

Figure 1: Peak Pulse Power vs. Pulse Time

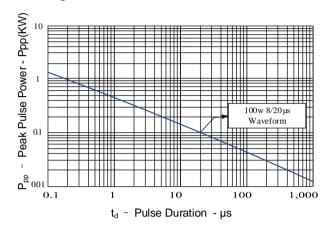


Figure 2: Power Derating Curve

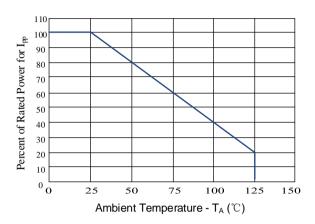


Figure 3: Clamping Voltage vs. Peak Pulse Current

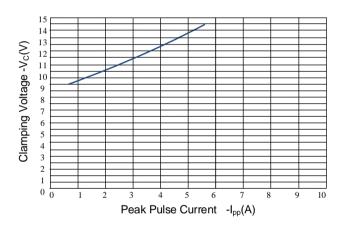


Figure 4: WS05MF Insertion Loss



Figure 5: Normalized Junction Capacitance vs. Reverse Voltage

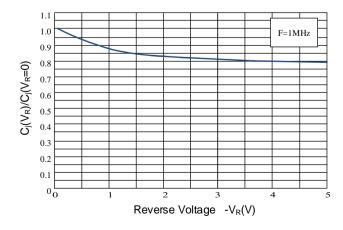
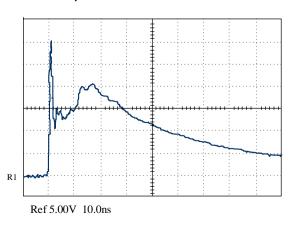
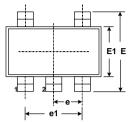


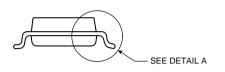
Figure 6: ESD Pulse Waveform (Per IEC 61000-4-2)

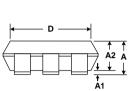


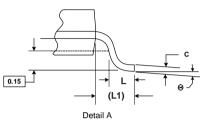
Outline Drawing - SOT-353

PACKAGE OUTLINE



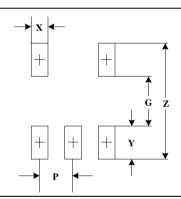








DIMENSIONS					Ì
SYMBOL	INCHES		MILLIN	/IETER	l
OTIVIDOL	MIN	MAX	MIN	MAX	
Α	0.035	0.043	0.900	1.100	
A1	0.000	0.004	0.000	0.100	
A2	0.035	0.039	0.900	1.000	Ī
D	0.079	0.087	2.000	2.200	
E1	0.045	0.053	1.150	1.350	
Е	0.085	0.096	2.150	2.450	Ì
е	0.020 TYP		0.650 TYP		l
e1	0.047	0.055	1.200	1.400	
L	0.022 REF		0.525	REF	
L1	0.010	0.018	0.260	0.460	_
θ	0°		8°	0°	



DIMENSIONS		
DIM	INCHES	MILLIMETERS
Z	0.090	2.30
G	0.073	1.85
Р	0.020 TYP	0.65 TYP
Х	0.008	0.20
Υ	0.033	0.085

- Dimensioning and tolerances per ANSI Y14.5M, 1985.
 Controlling Dimension: Inches
 Pin 3 is the cathode (Unidirectional Only).

- 4. Dimensions are exclusive of mold flash and metal burrs.

Marking Codes

Part Number	WS05MF
Marking Code	05F

Package Information

Qty: 3k/Reel

CONTACT INFORMATION

CYG WAYON CIRCUIT PROTECTION CO., LTD.

No.1001, Shiwan (7) Road, Pudong District, Shanghai, P.R.China.201202 Tel: 86-21-68969993 Fax: 86-21-50757680 Email: market@way-on.com

WAYON website: http://www.way-on.com

For additional information, please contact your local Sales Representative.

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Specifications are subject to change without notice. Specifications are subject to thange without mode.

The device characteristics and parameters in this data sheet can and do vary in different applications and actual device performance may vary over time. Users should verify actual device performance in their specific applications.